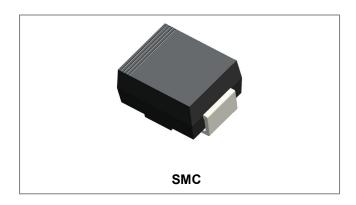






### **SK54 SCHOTTKY RECTIFIER**



#### **Features**

- Small foot print, surface mountable
- Very low forward Voltage Drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



## **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	40	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>L</sub> =75°C, rectangular wave form	5	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>c</sub> = 25 °C	125	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 5A, Pulse, T <sub>J</sub> = 25 °C	0.58	0.65	V
	V <sub>F2</sub>	@ 5A, Pulse, T <sub>J</sub> = 125 °C	0.50	0.63	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.01	1.0	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R_1} T_J = 125  ^{\circ}\text{C}$	8	30.0	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25  ^{\circ}C, f_{SIG} = 1MHz$	130	280	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%



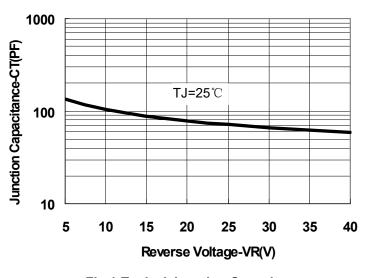




## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{\theta JA}$	DC operation	55	°C/W
Approximate Weight	wt	-	0.21	g

## **Ratings and Characteristics Curves**



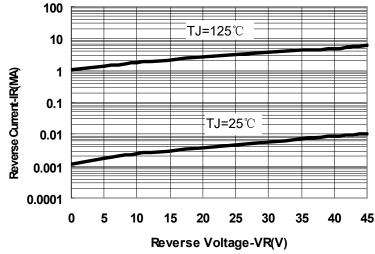


Fig.1-Typical Junction Capacitance

Fig.2-Typical Values Of Reverse Current

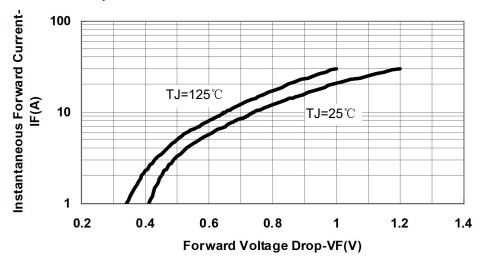


Fig.3-Typical Forward Voltage Drop Characteristics

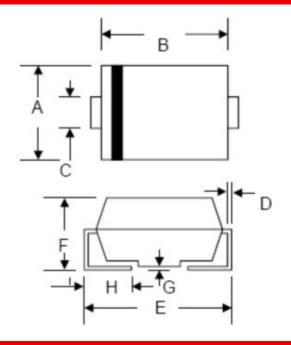
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### **Mechanical Dimensions SMC**



SYMBOL	Millin	neters	Inches		
STWIBUL	Min.	Max.	Min.	Max.	
Α	5.59	6.22	0.220	0.245	
В	6.60	7.11	0.260	0.280	
С	2.75	3.25	0.108	0.128	
D	0.152	0.305	0.006	0.012	
E	7.75	8.25	0.305	0.325	
F	2.00	2.95	0.079	0.116	
G	0.051	0.203	0.002	0.008	
Н	0.76	1.60	0.030	0.063	

# Ordering Information

Device	Package	Shipping
SK54	SMC (Pb-Free)	3000pcs / reel
SK54TR	SMC (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



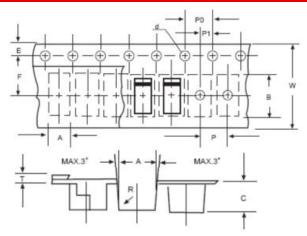
Where XXXXX is YYWWL

SK = Device Type
5 = Forward Current (5A)
4 = Reverse Voltage (40V)
YY = Year
WW = Week

= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## **Carrier Tape Specification SMC**



SYMBOL	Millimeters			
STIVIBUL	Min.	Max.		
Α	5.90	6.10		
В	8.20	8.40		
С	2.40	2.60		
d	1.40	1.60		
E	1.40	1.60		
F	7.60	7.70		
Р	7.90	8.10		
P0	3.90	4.10		
P1	3.90	4.10		
Т	-	0.600		
W	15.80	16.20		

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